

BoltzTraP2

Georg K. H. Madsen

Institute of Materials Chemistry, TU Wien, Austria

20-09-17 / WIEN2k-workshop



TECHNISCHE
UNIVERSITÄT
WIEN

Overview

- The Boltzmann transport equations
- BoltzTraP (Smoothed Fourier band interpolation)
- BoltzTraP2. A modern tool for modern workflows
 - Algorithm
 - Including the momentum matrix elements
 - Command-line interface and Python3 library: CoSb3
- Applications:
 - Volumetric band alignment
 - *p*-doped half-Heusler Compounds

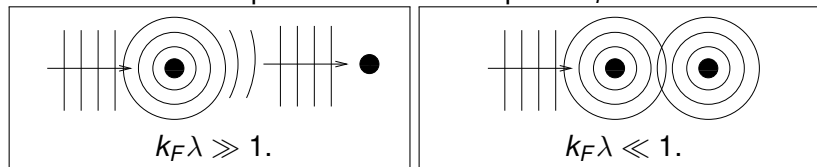
The Boltzmann equation

The *steady state* distribution f is constant in time

$$\left(\frac{\partial f}{\partial t}\right)_{\text{diff}} + \left(\frac{\partial f}{\partial t}\right)_{\text{field}} + \left(\frac{\partial f}{\partial t}\right)_{\text{scatt}} = 0$$

Assumption:

\mathbf{k} should be a good quantum number. i.e. wavelength of electron small compared to mean free path. $k_F \lambda \ll 1$.

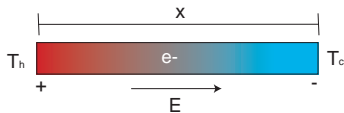


Boltzmann Equation

$$\left(\frac{\partial f}{\partial t}\right)_{\text{diff}} + \left(\frac{\partial f}{\partial t}\right)_{\text{field}} + \left(\frac{\partial f}{\partial t}\right)_{\text{scatt}} = 0$$

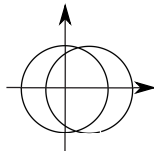
Diffusion:

$$\left(\frac{\partial f}{\partial t}\right)_{\text{diff}} = \frac{\partial f}{\partial T} \nabla T \mathbf{v}$$



Field:

$$\left(\frac{\partial f}{\partial t}\right)_{\text{field}} = -\frac{\partial f}{\partial \epsilon} \mathbf{v} q \mathbf{E}$$



$$\mathbf{v} \left(-\frac{\partial f}{\partial \epsilon} \right) \left(-\frac{\epsilon - \mu}{T} \nabla T + q \mathbf{E} \right) = -\left(\frac{\partial f}{\partial t}\right)_{\text{scatt}}$$

Relaxation time approximation

Phenomenological assumption: Exponential decay of deviation from equilibrium with τ as the relaxation time.

$$\left(\frac{\partial f}{\partial t}\right)_{scatt} = -\frac{f - f^{(0)}}{\tau}$$

thereby

$$j_e = \sum_n \int q v_{nk} v_{nk} \tau_{nk} \left(-\frac{\partial f^{(0)}}{\partial \epsilon}\right) \left(-\frac{\epsilon - \mu}{T} \nabla T + q \mathbf{E}\right) \frac{d\mathbf{k}}{8\pi^3}$$

$$j_Q = \sum_n \int (\epsilon - \mu) v_{nk} v_{nk} \tau_{nk} \tau_{nk} \left(-\frac{\partial f^{(0)}}{\partial \epsilon}\right) \left(-\frac{\epsilon - \mu}{T} \nabla T + q \mathbf{E}\right) \frac{d\mathbf{k}}{8\pi^3}$$

The transport distribution

Introduce the transport distribution

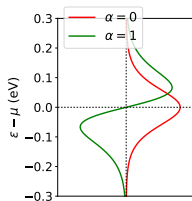
$$\sigma(\varepsilon) = \sum_n \int v_{nk} v_{nk} \tau_{nk} \delta(\varepsilon - \varepsilon_{nk}) \frac{dk}{8\pi^3}$$

The generalized transport coefficients are moments of the transport distribution

$$\mathcal{L}^{(\alpha)}(T, \mu) = q^2 \int \sigma(\varepsilon) (\varepsilon - \mu)^\alpha \left(-\frac{\partial f}{\partial \varepsilon} \right) d\varepsilon$$

$$-(\varepsilon - \mu)^\alpha \frac{\partial f}{\partial \varepsilon}$$

$$j_e = \mathcal{L}^{(0)} \mathbf{E} + \frac{\mathcal{L}^{(1)}}{qT} (-\nabla T)$$
$$j_Q = \frac{\mathcal{L}^{(1)}}{q} \mathbf{E} + \frac{\mathcal{L}^{(2)}}{q^2 T} (-\nabla T)$$



Phenomenological transport coefficients

Identify two kinds of experimental situations

$$\nabla T = \mathbf{0}:$$

$$j_e = \mathcal{L}^{(0)} E \Rightarrow \sigma = \mathcal{L}^{(0)}$$

$$j_Q = \frac{\mathcal{L}^{(1)}}{q} \mathbf{E} = \frac{\mathcal{L}^{(1)}}{q \mathcal{L}^{(0)}} j_e \Rightarrow \Pi = \frac{\mathcal{L}^{(1)}}{q \mathcal{L}^{(0)}}$$

$$\mathbf{j}_e = \mathbf{0}:$$

$$\mathcal{L}^{(0)} E = \frac{\mathcal{L}^{(1)}}{qT} \nabla T \Rightarrow S = \frac{1}{qT} \frac{\mathcal{L}^{(1)}}{\mathcal{L}^{(0)}}$$

$$j_Q = \frac{1}{q^2 T} \left(\frac{(\mathcal{L}^{(1)})^2}{\mathcal{L}^{(0)}} - \mathcal{L}^{(2)} \right) \nabla T \Rightarrow \kappa_e = \frac{1}{q^2 T} \left(\frac{(\mathcal{L}^{(1)})^2}{\mathcal{L}^{(0)}} - \mathcal{L}^{(2)} \right)$$

Harvesting of waste heat

- The thermoelectric effect is the direct conversion of temperature differences to electric voltage and vice-versa
- Approximately 70% of energy is lost as waste heat when burning fossil fuels for power generation

Figure of merit

$$zT = \frac{S^2 \sigma T}{\kappa_e + \kappa_l}$$

Electronic power factor

$$PF = S^2 \sigma$$



Shankland-Pickett algorithm

Constrained optimization procedure: Minimize roughness function with respect to the Fourier coefficients while exactly reproducing calculated eigenvalues.

$$\tilde{\epsilon}_{\mathbf{k}} = \sum_{\Lambda} c_{\Lambda} \sum_{R \in \Lambda} \exp(i\mathbf{k} \cdot \mathbf{R})$$

Minimize the Lagrangian

$$I = \frac{1}{2} \sum_{\Lambda} c_{\Lambda} \rho_{\Lambda} + \sum_{\mathbf{k}} \lambda_{\mathbf{k}} (\epsilon_{\mathbf{k}} - \tilde{\epsilon}_{\mathbf{k}})$$

Euwema, Shankland et al, Phys. Rev. 178 (1969) 1419–1423

Shankland, Int. J. Quantum Chem. 5 (1971) 497–500.

Roughness function

$$\rho = \left(\tilde{\epsilon}_{\mathbf{k}} - \epsilon_0 + C_1 \nabla^2 \tilde{\epsilon}_{\mathbf{k}} \right)^2$$

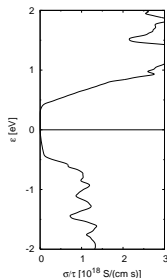
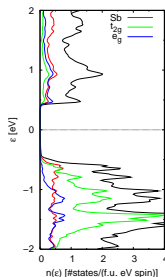
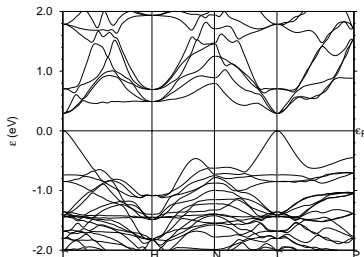
Pickett et al. Phys. Rev. B 38 (1988) 2721–2726.

Transport distribution. CoSb₃

Transport distribution

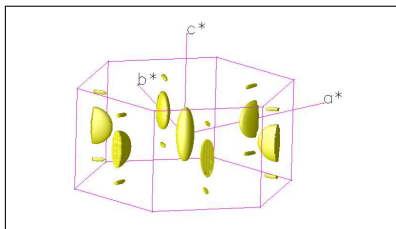
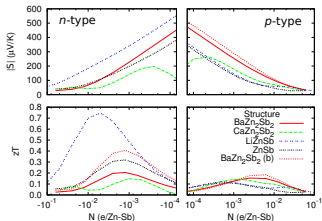
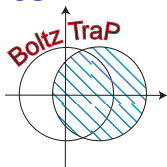
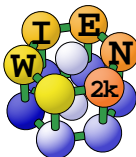
$$\sigma(\varepsilon) = \frac{1}{3} \sum_n \int v_{nk} v_{nk} \tau_{nk} \delta(\varepsilon - \varepsilon_{nk}) \frac{d\mathbf{k}}{8\pi^3}$$

CoSb₃



Automated search for new thermoelectrics

Inorganic Crystal Structure Database



- BoltzTrap:
 - All crystal structures
 - Full tensors quantities
 - Numerically efficient and stable

GKHM JACS **128** p12140 (2006)

GKHM, Singh, *Comput. Phys. Commun.* **175**, p67 (2006)

Bjerg, GKHM, Iversen, *Chem. Mat.* **23** p3907 (2011)

BoltzTraP2: A modern tool for modern workflows.

Design goals:

- All useful features from BoltzTraP
- Easy installation, portability
`pip3 install BoltzTraP2`
- Command-line interface (no config files)

Speed:

- New algorithms
- Modularity, flexibility
- Standard formats

Two use cases:

- 1 *I want to estimate the Onsager thermoelectric coefficients from my DFT results*
⇒ **BoltzTraP2 as a stand-alone tool**
- 2 *I need interpolated bands as inputs to my own algorithm*
⇒ **BoltzTraP2 as a Python module**

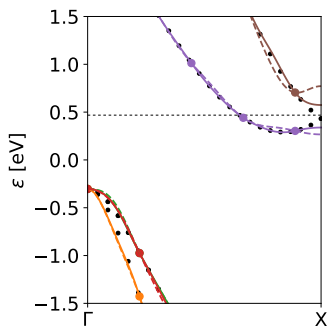
BoltzTraP2 interpolation

Minimize roughness function with respect to the Fourier coefficients while exactly reproducing calculated eigenvalues *and derivatives*

$$I = \frac{1}{2} \sum c_{\Lambda\rho\Lambda} + \sum_{\mathbf{k}} \lambda_{\mathbf{k}} (\varepsilon_{\mathbf{k}} - \tilde{\varepsilon}_{\mathbf{k}}) + \sum_{\mathbf{k}} \lambda'_{\mathbf{k}} (\nabla\varepsilon_{\mathbf{k}} - \nabla\tilde{\varepsilon}_{\mathbf{k}})$$

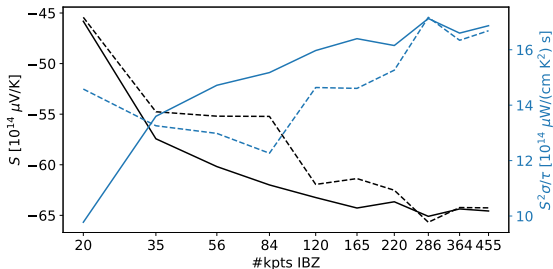
- Combine advantage of BoltzTraP (analytic bands) and Scheidemantel-Sofo approach (exact derivatives at calculated points)
- Potentially coarser k -mesh in ab-initio calculation

Example: Silicon band structure



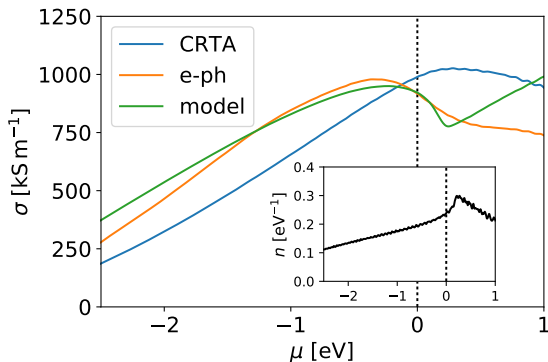
- CBM made up by degenerate pocket along six-fold degenerate $\Gamma - X$ line
- Interpolated bands based on a coarse $9 \times 9 \times 9$ k -point mesh
- Modified Lagrangian forces the fit to reproduce the exact derivatives at the calculated points.
- Position and derivatives at the pocket are well reproduced

Example: Silicon transport



- Seebeck coefficient and thermoelectric power factor calculated at a chemical potential close to the CBM using the CRTA
- The results obtained by the modified Lagrangian show both a faster and more systematic convergence towards the converged values
- Convergence reached at about half the number of k -points

Example: Band and momentum dependent relaxation times



- Including band and momentum dependent relaxation times changes the slope of the transport distribution (and thereby the Seebeck coefficient)

Some highlights of BoltzTraP2

Flexibility

- Usable as a Python module
- Extensible scattering models
- Automatic detection of space group

Speed

- Highly vectorized Python
- Symmetry module in C++
- fftw

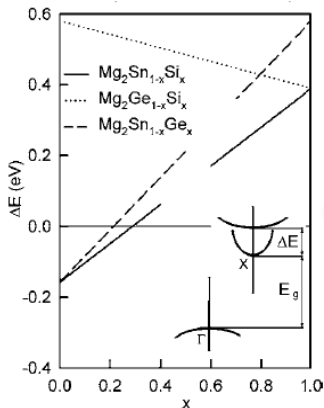
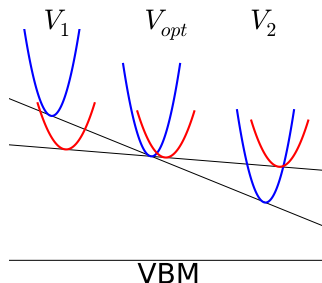
Portability

- Standard Python setup toolchain
- Detection of compilers and libraries
- Adherence to C++11

Standard formats

- JSON: Human readable & parsers for every language
- Final output as text

Volumetric Band Alignment



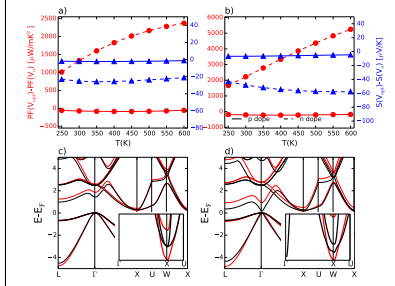
Zaitsev et al. *PRB* 74 p045207 (2006)

Optimize power factor by alignment of band edges

$$S^2\sigma = \frac{1}{q^2 T^2} \frac{(\mathcal{L}^{(1)} + \mathcal{L}^{(1)})^2}{\mathcal{L}^{(0)} + \mathcal{L}^{(0)}}$$

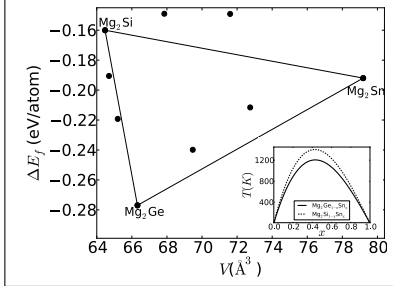
1. Band structure

Calculate volume dependence of S and σ/τ



2. Thermodynamics

Calculate mixing enthalpy (SQS)



VBA screening

Initial M-X combinations

3150

Thermodynamically stable structures

522

Good thermoelectrics
($zT > 0.4$)

29

Candidates for VBA

8

Checks for alloy stability

4

M-X
M-X

1 H 1.0079																	2 He 4.0026									
3 Li 6.941	4 Be 9.0122											5 B 10.811	6 C 12.011	7 N 14.007	8 O 15.999	9 F 18.998	10 Ne 20.180									
11 Na 22.990	12 Mg 24.305											13 Al 26.982	14 Si 28.086	15 P 30.974	16 S 32.065	17 Cl 35.453	18 Ar 39.948									
19 K 39.098	20 Ca 40.078	21 Sc 44.956	22 Ti 47.867	23 V 50.942	24 Cr 51.996	25 Mn 54.938	26 Fe 55.845	27 Co 58.933	28 Ni 58.693	29 Cu 63.546	30 Zn 65.38	31 Ga 69.723	32 Ge 72.64	33 As 74.922	34 Se 78.96	35 Br 79.904	36 Kr 83.798									
37 Rb 85.468	38 Sr 87.62	39 Y 88.906	40 Zr 91.224	41 Nb 92.906	42 Mo 95.94	43 Tc 98	44 Ru 101.07	45 Rh 102.91	46 Pd 106.42	47 Ag 107.87	48 Cd 112.41	49 In 114.82	50 Sn 118.71	51 Sb 121.76	52 Te 127.6	53 I 126.905	54 Xe 131.29									
55 Cs 132.91	56 Ba 137.33											57 La 138.905	58 Ce 140.12	59 Pr 140.908	60 Nd 144.24	61 Pm 144.913	62 Sm 150.36	63 Eu 151.964	64 Gd 157.25	65 Tb 158.925	66 Dy 162.50	67 Ho 164.930	68 Er 167.259	69 Tm 168.934	70 Yb 173.054	71 Lu 174.967
87 Fr [223]	88 Ra [226]											104 Rf [261]	105 Db [262]	106 Sg [263]	107 Bh [264]	108 Hs [265]	109 Mt [266]	110 Ds [267]	111 Rg [268]							

Alloy Thermodynamics

Compound	$\Delta E_h [\Delta E_h^{\text{Sn}}]$ (meV/atom)	V_{opt} (%)	x_{alloy}	$\Delta E_{\text{mix}}(0.25)$ (kJ/mol)	x (800 K)
$\text{Mg}_2\text{Si}_{1-x}\text{Sn}_x$	0[0]	2.0	0.09	1.997	0.171
$\text{Ca}_2\text{Si}_{1-x}\text{Sn}_x$	0[0]	5.0	0.30	0.013	all
$\text{Ca}_9\text{Ge}_{5-x}\text{Sn}_x$	37.4[17.9]	6.1	0.28	4.495	0.019
$\beta\text{-MoSi}_{2-x}\text{Sn}_x$	27.3[180.8]	3.0	0.07	30.980	0.008
$\text{o-Fe}_2\text{Ge}_{3-x}\text{Sn}_x$	0.1[22.5]	3.0	0.10	32.746	0.004

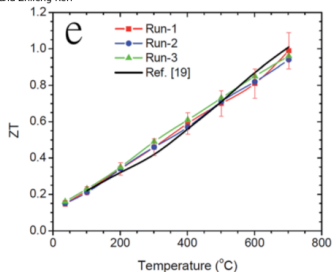
Bhattacharya, GKHM *Phys. Rev. B* 92, p085205 (2015)

p-type HHC: (V/Nb)FeSb

Cite this: *Energy Environ. Sci.*, 2014, 7, 4070

NbFeSb-based p-type half-Heuslers for power generation applications

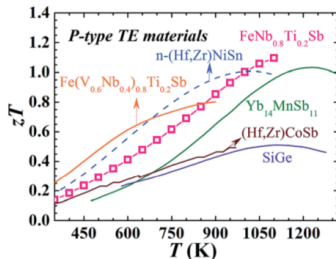
Giri Joshi,^{a*} Ran He,^b Michael Engler,^a Georgy Samsonidze,^c Tej Pantha,^a Ekraj Dahal,^a Keshab Dahal,^b Jian Yang,^a Yucheng Lan,^b Boris Kozinsky^c and Zhifeng Ren^{*ab}



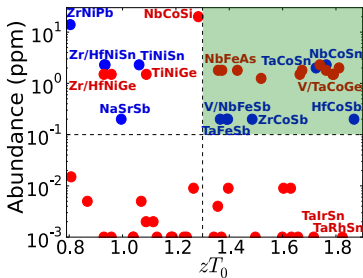
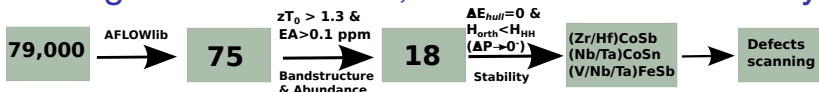
Cite this: *Energy Environ. Sci.*, 2015, 8, 256

Band engineering of high performance p-type FeNbSb based half-Heusler thermoelectric materials for figure of merit $zT > 1$ †

Chenguang Fu,^a Tiejun Zhu,^{*ab} Yintu Liu,^a Hanhui Xie^a and Xinbing Zhao^{ab}

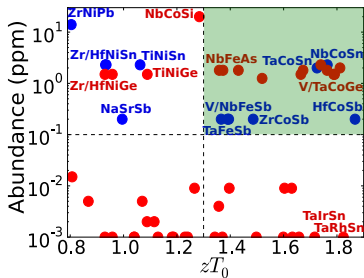


Screening. Band structure, abundance and stability.



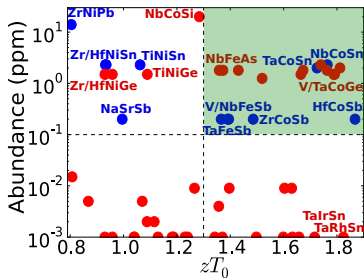
Compound	ΔE_{hull} meV/atom	orth phase
TaFeAs	33.03	yes
TaFeSb	0.00	no
NbFeAs	125.81	yes
NbFeSb	0.00	no
VFeSb	0.00	no
ZrCoAs	0.00	yes
ZrCoSb	0.00	no
WFeGe	64.34	no
NbCoGe	0.00	yes
HfCoAs	0.00	yes
TaCoSn	0.00	no
VCoSn	90.77	no
TiCoAs	0.00	yes
NbCoSn	0.00	no
TaCoGe	0.00	yes
VCoGe	0.00	yes
TaCoSi	91.47	yes
HfCoSb	0.00	no

Screening. Band structure, abundance and stability.



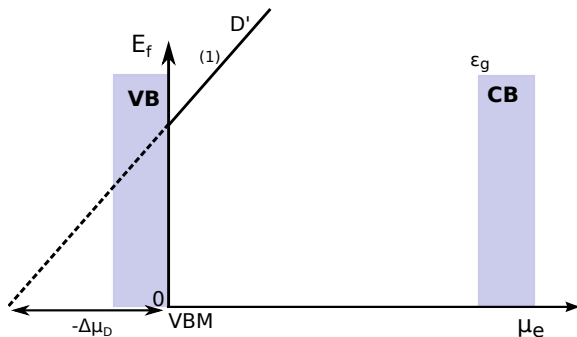
Compound	ΔE_{hull} meV/atom	orth phase
TaFeAs	33.03	yes
TaFeSb	0.00	no
NbFeAs	125.81	yes
NbFeSb	0.00	no
VFeSb	0.00	no
ZrCoAs	0.00	yes
ZrCoSb	0.00	no
V/NbFeSb	0.00	no
TaFeSb	0.00	no
HfCoSb	0.00	no
ZrCoSb	0.00	no
NaSrSb	0.00	no
TaRhSn	0.00	no
TaRhSn	0.00	no
ZrNiPb	0.00	no
NbCoSi	0.00	no
Zr/HfNiSn	0.00	no
TiNiSn	0.00	no
TiNiGe	0.00	no
NbFeAs	0.00	no
TaCoSn	0.00	no
NbCoSn	0.00	no
VFeSb	0.00	no
ZrCoAs	0.00	no
V/TaCoGe	0.00	no
HfCoSb	0.00	no
V/NbFeSb	0.00	no
TaFeSb	0.00	no
ZrCoSb	0.00	no
WFeGe	64.34	no
NbCoGe	0.00	yes
HfCoAs	0.00	yes
TaCoSn	0.00	no
VCoSn	90.77	no
TiCoAs	0.00	yes
NbCoSn	0.00	no
TaCoGe	0.00	yes
VCoGe	0.00	yes
TaCoSi	91.47	yes
HfCoSb	0.00	no

Screening. Band structure, abundance and stability.



Compound	ΔE_{hull} meV/atom	orth phase
TaFeAs	33.03	yes
TaFeSb	0.00	no
NbFeAs	125.81	yes
NbFeSb	0.00	no
VFeSb	0.00	no
ZrCoAs	0.00	yes
ZrCoSb	0.00	no
WFeGe	64.34	no
NbCoGe	0.00	yes
HfCoAs	0.00	yes
TaCoSn	0.00	no
VCoSn	90.77	no
TiCoAs	0.00	yes
NbCoSn	0.00	no
TaCoGe	0.00	yes
VCoGe	0.00	yes
TaCoSi	91.47	yes
HfCoSb	0.00	no

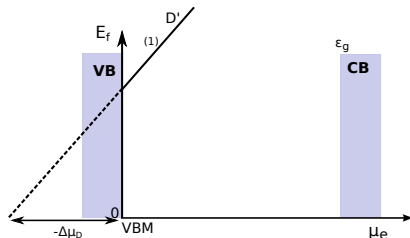
Intrinsic defects



	$\Delta\mu_{D'}$ (eV)	$D'^{(q)}$		$\Delta\mu_{D'}$ (eV)	$D'^{(q)}$		$\Delta\mu_{D'}$ (eV)	$D'^{(q)}$
NbCoSn	-0.27	Co _{Int} ⁽³⁾	VFeSb	-0.18	Fe _{Int} ⁽²⁾	ZrCoSb	-0.51	Sb _{Zr} ⁽¹⁾
TaCoSn	-0.26	Co _{Int} ⁽²⁾	NbFeSb	-0.60	Fe _{Int} ⁽²⁾	HfCoSb	-0.37	Co _{Int} ⁽²⁾

No intrinsic doping limits

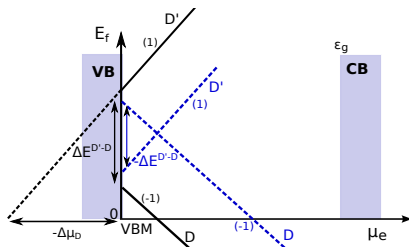
Extrinsic doping



	$E_f^D (\mu_{VB})$ (eV)	$D(q)$	$\Delta E^{D'-D}$ (eV)	$D'(q)$
NbFeSb	-0.01	Hf _{Nb} ⁽⁻¹⁾	1.20	Fe _{Int} ⁽²⁾
	0.09	Ti _{Nb} ⁽⁻¹⁾	1.10	Fe _{Int} ⁽²⁾
	0.21	Mn _{Fe} ⁽⁻¹⁾	0.72	Vac _{Fe} ⁽²⁾
	0.41	Zr _{Nb} ⁽⁻¹⁾	0.78	Fe _{Int} ⁽²⁾
	0.55	Sn _{Sb} ⁽⁻¹⁾	0.70	Fe _{Int} ⁽²⁾
ZrCoSb	0.17	Sc _{Zr} ⁽⁻¹⁾	0.60	Sb _{Zr} ⁽¹⁾
	0.61	Sn _{Sb} ⁽⁻¹⁾	0.35	Vac _{Co} ⁽¹⁾
	0.61	Fe_{Co}⁽⁻¹⁾	-0.48	Vac_{Co}⁽¹⁾
NbCoSn	0.32	Hf _{Nb} ⁽⁻¹⁾	0.50	Co _{Int} ⁽³⁾
	0.62	Fe_{Co}⁽⁻¹⁾	-0.15	Fe_{Int}⁽²⁾
	0.68	Ti _{Nb} ⁽⁻¹⁾	0.14	Co _{Int} ⁽³⁾
	0.72	Zr _{Nb} ⁽⁻¹⁾	0.10	Co _{Int} ⁽³⁾
TaCoSn	0.44	Hf _{Ta} ⁽⁻¹⁾	0.33	Co _{Int} ⁽²⁾
	0.87	Fe_{Co}⁽⁻¹⁾	-0.10	Fe_{Int}⁽²⁾

- Known carrier inducing defects reproduced in NbFeSb and ZrCoSb
- A new system with favorable extrinsic dopants identified

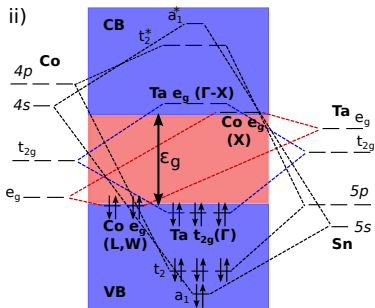
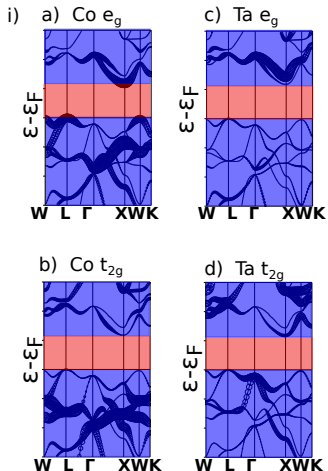
Extrinsic doping



	$E_f^D (\mu_{VB})$ (eV)	$D(q)$	$\Delta E^{D'-D}$ (eV)	$D'(q)$
NbFeSb	-0.01	Hf _{Nb} ⁽⁻¹⁾	1.20	Fe _{Int} ⁽²⁾
	0.09	Ti _{Nb} ⁽⁻¹⁾	1.10	Fe _{Int} ⁽²⁾
	0.21	Mn _{Fe} ⁽⁻¹⁾	0.72	Vac _{Fe} ⁽²⁾
	0.41	Zr _{Nb} ⁽⁻¹⁾	0.78	Fe _{Int} ⁽²⁾
	0.55	Sn _{Sb} ⁽⁻¹⁾	0.70	Fe _{Int} ⁽²⁾
ZrCoSb	0.17	Sc _{Zr} ⁽⁻¹⁾	0.60	Sb _{Zr} ⁽¹⁾
	0.61	Sn _{Sb} ⁽⁻¹⁾	0.35	Vac _{Co} ⁽¹⁾
	0.61	Fe_{Co}⁽⁻¹⁾	-0.48	Vac_{Co}⁽¹⁾
NbCoSn	0.32	Hf _{Nb} ⁽⁻¹⁾	0.50	Co _{Int} ⁽³⁾
	0.62	Fe_{Co}⁽⁻¹⁾	-0.15	Fe_{Int}⁽²⁾
	0.68	Ti _{Nb} ⁽⁻¹⁾	0.14	Co _{Int} ⁽³⁾
	0.72	Zr _{Nb} ⁽⁻¹⁾	0.10	Co _{Int} ⁽³⁾
TaCoSn	0.44	Hf _{Ta} ⁽⁻¹⁾	0.33	Co _{Int} ⁽²⁾
	0.87	Fe_{Co}⁽⁻¹⁾	-0.10	Fe_{Int}⁽²⁾

- Known carrier inducing defects reproduced in NbFeSb and ZrCoSb
- A new system with favorable extrinsic dopants identified

TE Heusler. Band structure.



- Alignment of pockets at L and W (and Γ)

Installing Anaconda and BoltzTraP2

```
ssh -X wienXXX@psiXX.theochem.tuwien.ac.at
wget https://repo.anaconda.com/archive/Anaconda3-2019.07-Linux-x86_64.sh
chmod u+x Anaconda3-2019.07-Linux-x86_64.sh
bash
./Anaconda3-2019.07-Linux-x86_64.sh
# Complete the installation procedure and init
# Log out of and log into the machine.
conda config --set auto_activate_base false
conda install cmake git vtk pytest
pip install pyfftw
pip install boltztrap2
# Now, to download the example data:
git clone https://gitlab.com/sousaw/BoltzTraP2.git
tar -xvf BoltzTraP2/data.tar.xz
```

Command Line Interface

Make working directory and copy data. Activate Conda if you have switched the autoconfig off.

Fit the calculated eigenvalues. The interpolated k -mesh should be five times as dense as the original:

```
btp2 interpolate . -m 5 -o CoSb3.bt2
```

Integrate to get the transport properties

```
btp2 integrate CoSb3.bt2 50:500:50
```

Plot the results

```
btp2 plot -c '["xx"]' CoSb3.btj S
```

[Read the wiki](#)

Acknowledgements

Sandip Bhattacharya



Jesús Carrete



Matthieu Verstraete

